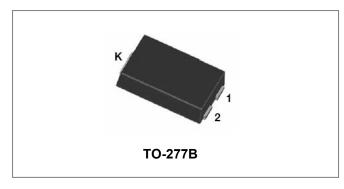


MBR1560S

Technical Data Data Sheet N1378, Rev. B

RoHS HF

MBR1560S SCHOTTKY RECTIFIER

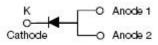


Features

- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram

Maximum Ratings:



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Characteristics Symbol Condition Max. Units Peak Repetitive Reverse Voltage V_{RRM} Working Peak Reverse Voltage V_{RWM} 60 V DC Blocking Voltage V_R 50% duty cycle @Tc=80°C, Average Rectified Forward Current I_{F (AV)} 15 А rectangular wave form Peak One Cycle Non-Repetitive Surge 8.3ms, Half Sine pulse, Tc=25°C IFSM 250 А Current

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V _{F1}	@ 15A, Pulse, T _J = 25 °C	0.54	0.59	V
	V _{F2}	@ 15A, Pulse, T _J = 125 °C	0.56	-	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	-	0.2	mA
	I _{R2}	@V _R = rated V _R T _J = 125 °C	12	-	mA
Junction Capacitance	Cj	@V _R = 5.0 V, Tc=25°C f _{SIG} = 1MHz		850	pF

* Pulse width < 300 $\mu s, \ duty \ cycle < 2\%$

http://www.smc-diodes.com - sales@ smc-diodes.com -



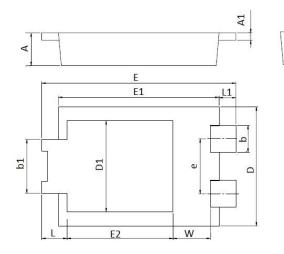
MBR1560S

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Soldering Point	$R_{ heta JS}$	DC operation	1.5	°C/W
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	2.3	°C/W
Approximate Weight	wt	-	0.08	g

Mechanical Dimensions TO-277B



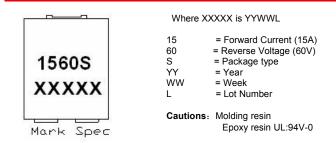
SYMBOL	Millimeters		Inches	
STMBOL	Min.	Max.	Min.	Max.
A	0.95	1.25	0.037	0.049
A1	0.20	0.30	0.008	0.012
b	0.85	0.95	0.033	0.037
b1	1.70	1.90	0.067	0.075
D	3.88	4.08	0.153	0.161
D1	2.90	3.20	0.114	0.126
е	1.74	1.94	0.069	0.076
E	6.30	6.70	0.248	0.264
E1	5.28	5.48	0.208	0.216
E2	3.40	3.70	0.134	0.146
L	0.70	1.00	0.028	0.039
L1	0.41	0.71	0.016	0.028
W	1.10	1.40	0.043	0.055

Ordering Information

Device	Package	Shipping
MBR1560S	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

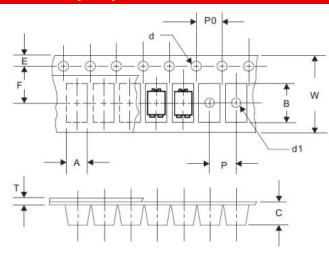




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Carrier Tape Specification TO-277B



SYMBOL	Millimeters		
STIVIDOL	Min.	Max.	
A	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

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